

Data Sheet January 2000 File Number 3614.5

4A, 200V Ultrafast Diodes

The RURD420 and RURD420S are ultrafast diodes with soft recovery characteristics (t_{rr} < 30ns). They have low forward voltage drop and are ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, reducing power loss in the switching transistors.

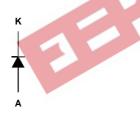
Formerly developmental type TA49034.

Ordering Information

PART NUMBER	PACKAGE	BRAND		
RURD420	TO-251	RUR420		
RURD420S	TO-252	RUR420		

NOTE: When ordering, use the entire part number. Add the suffix 9A to obtain the TO-252 variant in tape and reel, i.e., RURD42059A.

Symbol



Features

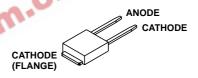
- · Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC STYLE TO-251



JEDEC STYLE TO-252



RURD420

Absolute Maximum Ratings $T_C = 25^{\circ}C$, Unless Otherwise Specified

RURD420S	UNITS
200	V
200	V
200	V
4	Α
8	Α
40	Α
30	W
10	mJ
-65 to 175	oC
300	oC
260	oC
	200 200 200 4 8 40 30 10 -65 to 175

RURD420, RURD420S

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 4A	-	-	1.0	V
	$I_F = 4A, T_C = 150^{\circ}C$	-	-	0.83	V
I _R	V _R = 200V	-	-	100	μΑ
	V _R = 200V, T _C = 150°C	-	-	500	μΑ
t _{rr}	I _F = 1A, dI _F /dt = 100A/μs	-	-	30	ns
	$I_F = 4A$, $dI_F/dt = 100A/\mu s$	-	-	35	ns
ta	$I_F = 4A$, $dI_F/dt = 100A/\mu s$	-	11	-	ns
t _b	$I_F = 4A$, $dI_F/dt = 100A/\mu s$	-	9	-	ns
Q _{RR}	$I_F = 4A$, $dI_F/dt = 100A/\mu s$	-	12	-	nC
СЈ	V _R = 10V, I _F = 0A	-	15	-	pF
$R_{ heta JC}$		-	-	5	°C/W
DEFINITIONS		a straight line from	3 %		
V _F = Instantaneo	us forward voltage (pw = 300μs, D = 2%).	- 4	4		
I _R = Instantaneo	us reverse current.	a 18 9	CI		
t _{rr} = Reverse rec	overy time (See Figure 8), summation of t _a + t _b .	22 3	0.		
t _a = Time to read	ch peak reverse current (See Figure 8).	1.35			
t _b = Time from p	eak I_{RM} to projected zero crossing of I_{RM} based on	a straight line from	peak I _{RM} through	1 25% of I _{RM} (Se	e Figure 8).
Q _{RR} = Reverse red					
•					

DEFINITIONS

C_J = Junction capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

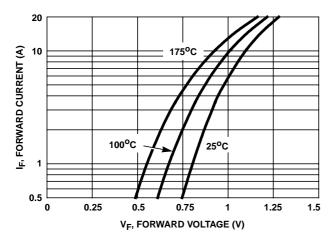


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

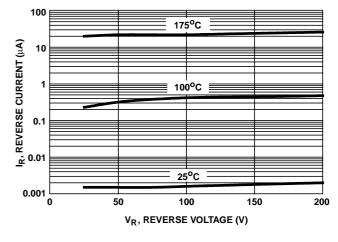


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

RURD420, RURD420S

Typical Performance Curves (Continued)

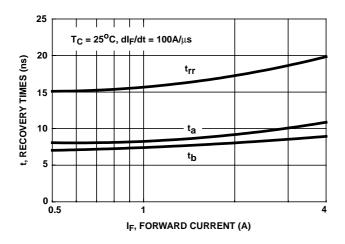


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

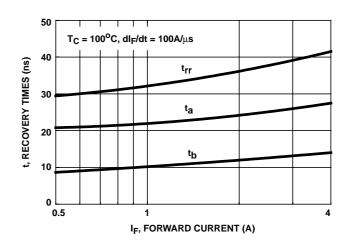


FIGURE 4. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

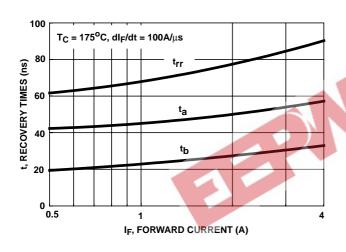


FIGURE 5. t_{rr} , t_a and t_b curves vs forward current

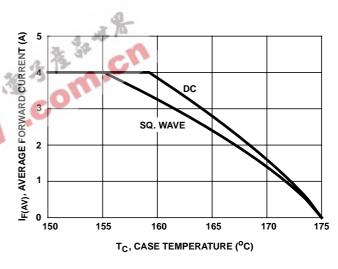


FIGURE 6. CURRENT DERATING CURVE

Test Circuits and Waveforms

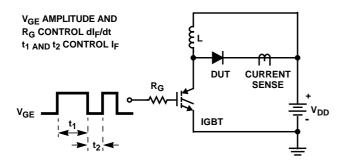


FIGURE 7. t_{rr} TEST CIRCUIT

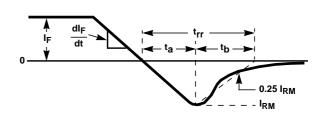


FIGURE 8. t_{rr} WAVEFORMS AND DEFINITIONS

RURD420, RURD420S

Test Circuits and Waveforms (Continued)

I = 1A L = 20mH $R < 0.1\Omega$ $E_{AVL} = 1/2LI^2 \left[V_{R(AVL)} / (V_{R(AVL)} - V_{DD}) \right]$ $Q_1 = IGBT \left(BV_{CES} > DUT \ V_{R(AVL)} \right)$ Q_1 Q_1

FIGURE 9. AVALANCHE ENERGY TEST CIRCUIT

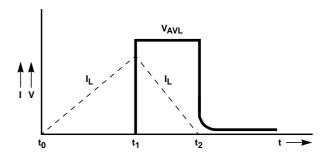


FIGURE 10. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



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